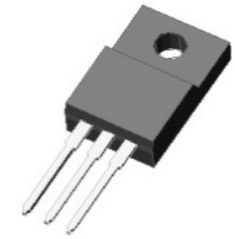
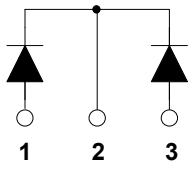
Ultrafast Recovery Power Rectifier

Features and Benefits

- Low forward drop voltage
- Dual common cathode rectifier construction
- Ultrafast recovery time and high speed switching
- Full lead (Pb)-free device and RoHS compliant device





Pin 1, 3 : Anode
Pin 2: Cathode

TO-220F-3L

Applications

- Switching power supply
- Power inverters
- Power conversion system

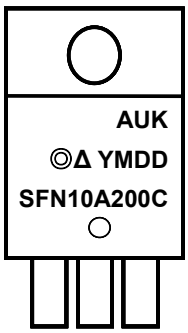
General Description

The SFN10A200C is ideally as boost diode in discontinuous or critical mode power factor corrections. The planar structure and the platinum doper life time control guarantee the best overall performance, ruggedness reliability characteristics. The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

Ordering Information

Part Number	Marking Code	Package	Packaging
SFN10A200C	SFN10A200C	TO-220F-3L	Tube

Marking Information



Column 1: Manufacturer

Column 2: Production Information

e.g.) ◎△YMDD

-. ◎△: Factory Management Code

-. YMDD: Date Code (Year, Month, Daily)

Column 3: Device Code

Absolute Maximum Ratings (Limiting values at 25°C, unless otherwise specified)

Characteristic		Symbol	Ratings	Unit
Maximum repetitive reverse voltage Maximum working peak reverse voltage Maximum DC blocking voltage		V_{RRM} V_{RWM} V_R	200	V
Maximum average forward rectified current	Per diode	$I_{F(AV)}$	5	A
	Total device		10	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load per diode		I_{FSM}	120	A
Storage temperature range		T_{stg}	-45 to +150	℃
Maximum operating junction temperature		T_J	150	

Thermal Characteristics (Per diode)

Characteristic	Symbol	Ratings	Unit
Maximum thermal resistance	$R_{th(J-C)}$	4.0	°C/W
	$R_{th(J-A)}$	62.5	

Electrical Characteristics (Per diode)

Characteristic	Symbol	Test Condition		Min.	Typ.	Max.	Unit
Peak forward voltage drop	V_{FM} [1)]	I_{FM} = 5A	T_J=25℃	-	0.88	0.98	V
Reverse leakage current	I_{RM} [2)]	$V_R = V_{RRM}$	T_J=25℃	-	-	5	uA
			T_J=125℃	-	-	200	
Reverse recovery time	t_{rr}	I_F = 1A, di/dt = -100 A/us		-	17	25	ns
Junction capacitance	C_j	V_R = 10V_{DC}, f=1MHz		-	32	-	pF

[1)] Pulse test: $t_p \leq 380us$, Duty cycle≤2%

[2)] Pulse test: $t_p \leq 20ms$, Duty cycle≤2%

Typical Electrical Characteristic Curves (Per diode)

Fig. 1) Typical Forward Characteristics

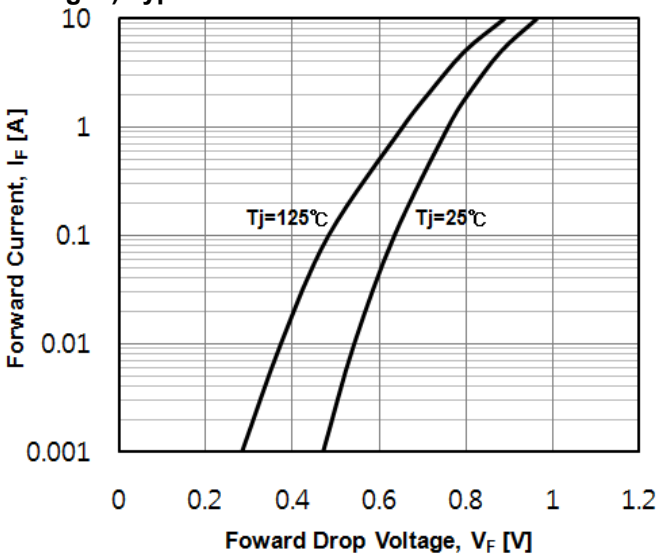


Fig. 2) Typical Reverse Characteristics

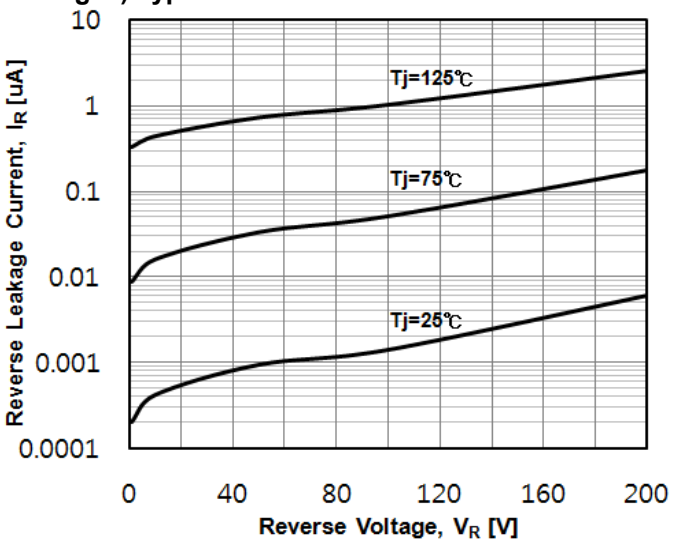


Fig. 3) Typical Junction Capacitance Characteristics

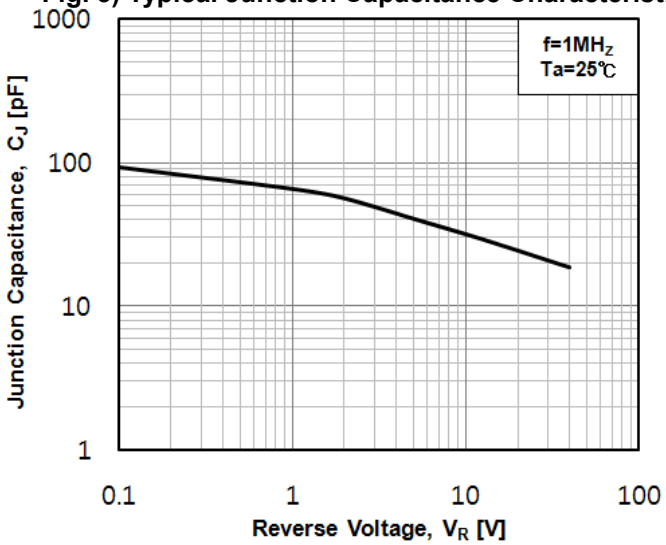


Fig. 4) Peak Forward Surge Current Characteristics

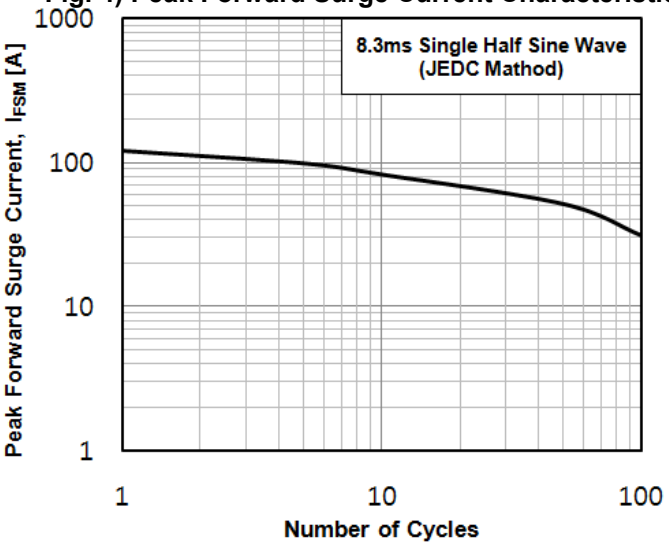


Fig. 5) Thermal Impedance Characteristics

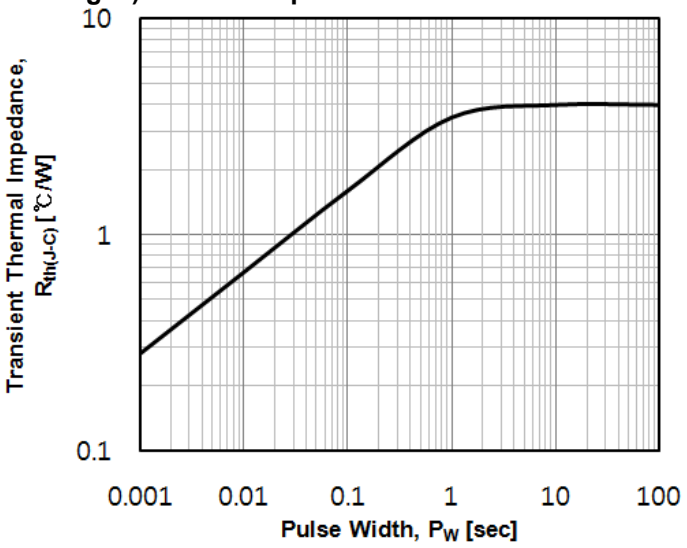
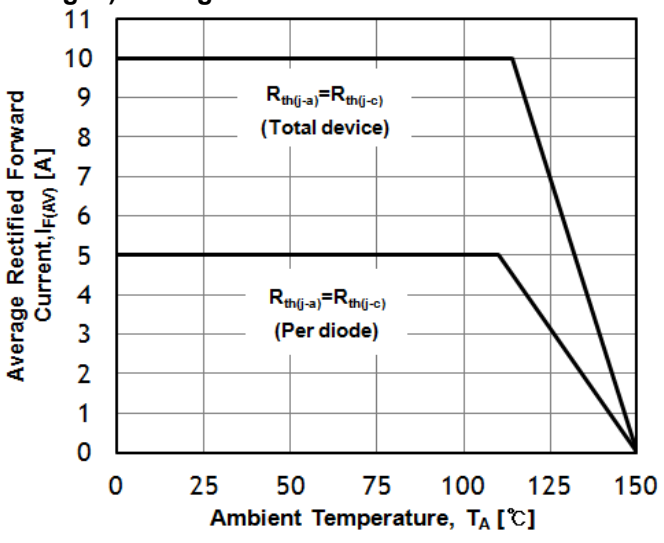
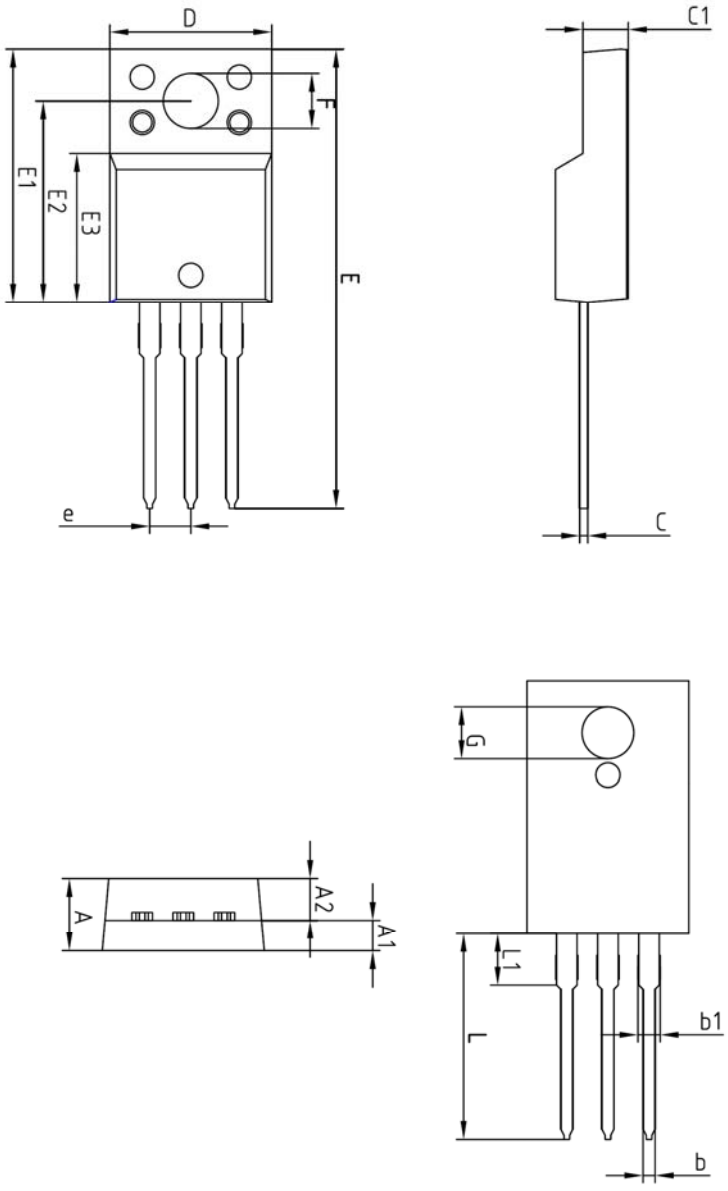


Fig. 6) Average Forward Current Characteristics



Package Outline Dimensions (Unit: mm)



SYMBOL	MILLIMETERS			NOTE
	MINIMUM	NOMINAL	MAXIMUM	
A	–	–	4.60	
A1	2.45	2.50	2.55	
A2	1.95	2.00	2.05	
b	0.65	0.75	0.85	
b1	1.07	1.27	1.47	
C	0.40	0.50	0.60	
C1	2.70	2.80	2.90	
D	9.90	10.00	10.10	
E	28.00	–	28.60	
E1	15.50	15.60	15.70	
E2	12.30	12.40	12.50	
E3	9.15	9.20	9.25	
F	3.30	3.40	3.50	
G	3.10	3.20	3.30	
e	2.34	2.54	2.74	
L	12.40	–	13.00	
L1	3.00	3.20	3.40	

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